Examiner-Initiated Interview Summary	Application No.	Applicant(s)
	10/796,655	HORIKOSHI, HIROSHI
	Examiner	Art Unit
	Thanhha Pham	2813
All Participants:	Status of Applicatio	n:
(1) <u>Thanhha Pham</u> .	(3)	
(2) Christopher Rausch.	(4)	
Date of Interview: 13 September 2006	Time:	
Type of Interview: Telephonic Video Conference Personal (Copy given to: Applicant Applicant Applicant Shown or Demonstrated: Yes No If Yes, provide a brief description:	icant's representative)	
Part I.		
Rejection(s) discussed:		
Claims discussed: 1-20 Prior art documents discussed:		
Part II. SUBSTANCE OF INTERVIEW DESCRIBING THE GEN	IEDAL NATURE OF WHA	T WAS DISCUSSED:
Discuss claimed languages to overcome 112 2 nd paragraph re		
Part III.		
 ☐ It is not necessary for applicant to provide a separat directly resulted in the allowance of the application. of the interview in the Notice of Allowability. ☑ It is not necessary for applicant to provide a separat did not result in resolution of all issues. A brief summ 	The examiner will provide a e record of the substance	a written summary of the substance of the interview, since the interview
(Examiner/SPE Signature) (Application	ant/Annlicant's Representa	tive Signature – if appropriate)
(Application Control C	and applicant 5 Representa	are digitatare in appropriate)

Interview summary dated 9/13/06

In claim 1,

Line 2, delete "the"

Line 8, change "a second wiring" to - second wirings -

Line 8, change "it is" to – they are –

Line 8, after "wherein" insert - one of --

Line 9, change "wiring" (1st occurrence) to - wirings -

Line 9, change "the memory element" to – the magnetoresistance effect type memory element –

Line 10, change "the memory element" to – the magnetoresistance effect type memory element –

Line 10, after "comprises" delete "the"

Line 12, change "a side portion" to - side portions -

Line 12, change "the second wiring" to - the second wirings -

Line 13, change "wiring" to - wirings -

Line 15, change "the second wiring," to - each of the second wirings, -

In claim 4,

Line 3, change "portion" to – portions –

Line 3, change "wiring" to - wirings -

Line 6, change "portion" to – portions –

Line 6, change "wiring" to - wirings -

Line 7, change "wiring" to - wirings -

In claim 5,

Line 3, change "said second wiring is" to – said second wirings are –

Line 3, change "a trench formed on" to - trenches formed in -

Line 3, change "a barrier layer" to – barrier layers –

Line 5, change "said barrier layer" to - said barrier layers -

Line 5, change "the side portion of the second wiring is" to – the side portions of the second wirings are –

In claim 6,

Line 3, change "said second wiring is formed in a trench formed on" to -- said second wirings are formed in trenches in -

Line 3, change "a barrier layer" to – barrier layers –

Line 4, change "the step" to – a step –

Line 7, change "the surface of the second wiring" to – the side surface and the top surface of each of the second wirings –

Line 10, change "the second wiring" to - each of the second wirings -

In claim 7,

Line 3, change "said second wiring is formed in a trench formed on" to -- said second wirings are formed in trenches in -

Line 3, change "a barrier layer" to – barrier layers –

Line 5, change "the steps of" to - steps of -

Line 8, change "the surface of the second wiring" to – the side surface and the top surface of each of the second wirings –

Line 9, delete "the"

Line 11, change "the second wiring" to – each of the second wirings –

Cancel claims 8-20